

## T489D106M035ATA800

T489 Auto, Tantalum, MnO<sub>2</sub> Tantalum, 10  $\mu$ F, 20%, 35 VDC, SMD, MnO<sub>2</sub>, Molded, Low Leakage, Auto, AEC-Q200, 800 mOhms, 7343, Height Max = 3.1mm

CATHODE (-) END VIEW



SIDE VIEW



ANODE (+) END VIEW



BOTTOM VIEW



Click [here](#) for the 3D model.

### Dimensions

Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

### General Information

Series	T489 Auto
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, Low Leakage, Auto, AEC-Q200
Features	Low Leakage, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Component Weight	446.844 mg

### Specifications

Capacitance	10 $\mu$ F
Capacitance Tolerance	20%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
Resistance	800 mOhms (100kHz 25C)
Ripple Current	433 mA (rms, 100kHz 25C)
Leakage Current	2.6 $\mu$ A (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.